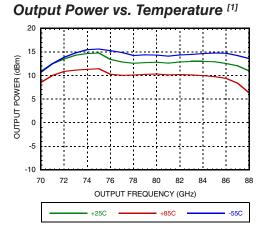
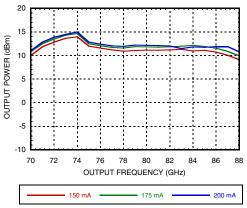




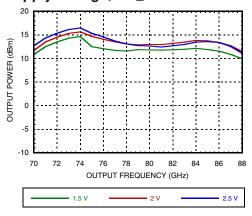
GaAs MMIC X6 ACTIVE FREQUENCY MULTIPLIER, 71 - 86 GHz



Output Power vs. VD_AMP Supply Current, VD_AMP = +4V ^[1]

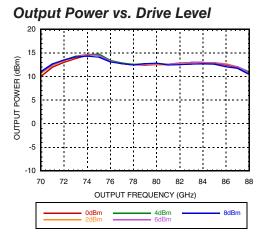


Output Power vs. VD_MULT Supply Voltage, VD_AMP = +4V^[1]



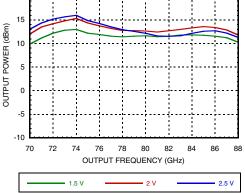
[1] Drive Level = +4 dBm

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Output Power vs. VD_AMP Supply Current, VD_AMP = +3V^[1] 20 15 OUTPUT POWER (dBm) 10 -5 -10 72 86 76 78 80 82 84 88 70 74 OUTPUT FREQUENCY (GHz) 150 mA 175 mA 200 mA

Output Power vs. VD_MULT Supply Voltage, VD_AMP = +3V^[1]



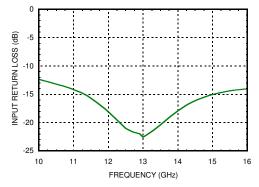
FREQUENCY MULTIPLIER - ACTIVE - CHIP

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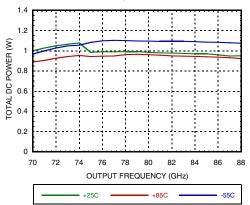




Input Return Loss



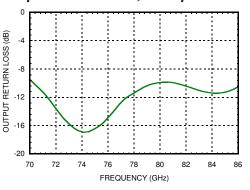
DC Power vs. Temperature, Pin = 4dBm VD_MULT = +1.5V, VD_AMP = +4V



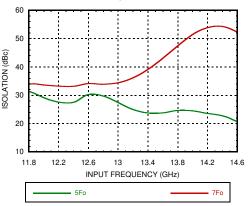


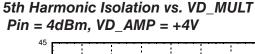
MULTIPLIER, 71 - 86 GHz

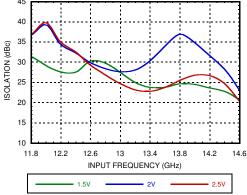
GaAs MMIC X6 ACTIVE FREQUENCY



5th & 7th Harmonic Isolation, Pin = 4dBm VD_MULT = +1.5V, VD_AMP = +4V







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GaAs MMIC X6 ACTIVE FREQUENCY MULTIPLIER, 71 - 86 GHz

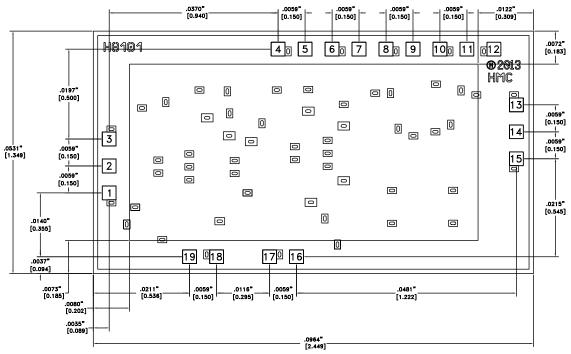
Absolute Maximum Ratings

	•		
Amplifier Drain Bias Voltage (VD_AMP)	+4.5 V		
Multiplier Drain Bias Voltage (VD_MULT)	+3V		
RF Input Power	+10 dBm		
Junction Temperature	146 °C		
Channel Temperature	175 °C		
Continuous Pdiss (T=85 °C) (derate=17.21 mW/ °C above 85°C)	1.55 W		
Thermal Resistance (R _{TH}) (junction to die bottom)	58.1 °C/W		
Operating Temperature	-55 °C to +85 °C		
Storage Temperature	-65 °C to 150 °C		
ESD Sensitivity (HBM)	Class 0, passed 150V		



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing



Die Packaging Information [1]

Standard	Alternate	
GP-2 (Gel Pack)	[2]	

[1] Refer to the "Packaging Information" section for die packaging dimensions.

[2] For alternate packaging information contact Hittite Microwave Corporation.

NOTES:

- 1. ALL DIMENSIONS ARE IN INCHES [MM]
- 2. DIE THICKNESS IS .004"
- 3. TYPICAL BOND PAD IS 0.0051" [3.303] SQUARE
- 4. BACKSIDE METALLIZATION: GOLD
- 5. BOND PAD METALLIZATION: GOLD
- 6. BACKSIDE METAL IS GROUND.
- 7. CONNECTION NOT REQUIRED FOR UNLABELED BOND PADS.
- 8. OVERALL DIE SIZE ± .002

FREQUENCY MULTIPLIER - ACTIVE - CHIP

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GaAs MMIC X6 ACTIVE FREQUENCY MULTIPLIER, 71 - 86 GHz

Pad Descriptions

Pad Number	Function	Description	Pin Schematic
1, 3, 4, 6, 8, 10, 12, 13, 15, 17, 18	GND	Ground pads must be connected to RF/DC ground.	
2	LO_IN	This pin is DC coupled and matched to 50 Ohms.	
5	VD_MULT	Supply voltage for multiplier. External bypass capacitors of 100 pF, 0.01 µF and 4.7 µF are recommended.	O VD_AMP1, VD_AMP2, ↓ VD_MULT
7, 11	VD_AMP1, VD_AMP2	Supply voltage for input and output amplifiers. External bypass capacitors of 100 pF, 0.01µF and 4.7 µF are recommended.	
9	VG_AMP	Gate control for amplifier. External bypass capacitors of 100pF, 0.01µF and 4.7µF are required. Adjust VG_AMP between -2 to 0V to achieve 175 mA total on VD_AMP1 and VD_AMP2.	
16, 19	VG_X2, VG_X3	Gate control for multiplier. External bypass capacitors of 100 pF, 0.01 μF and 4.7 μF are recommended. Adjust VG_X2, VG_X3 between -2 to 0V to achieve 1 - 2 mA on VD_MULT.	VG_AMP VG_X2, X3
14	LO_OUT	This pin is AC coupled and matched to 50 Ohms.	
Die Bottom	GND	Die bottom must be connected to RF/DC ground.	

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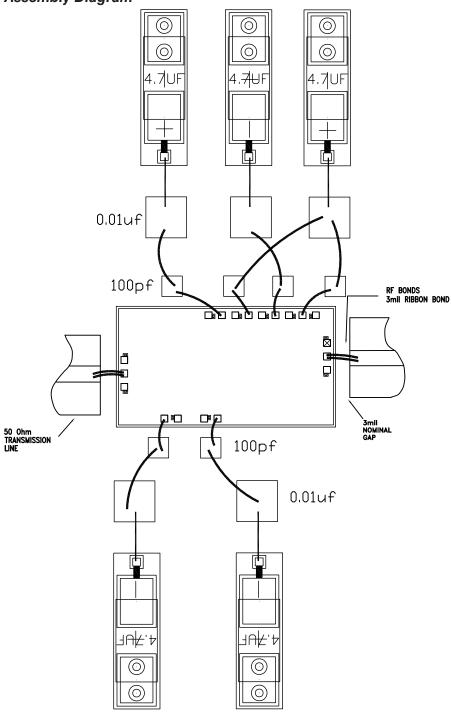
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GaAs MMIC X6 ACTIVE FREQUENCY MULTIPLIER, 71 - 86 GHz

Assembly Diagram



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GaAs MMIC X6 ACTIVE FREQUENCY MULTIPLIER, 71 - 86 GHz

Mounting & Bonding Techniques for Millimeterwave GaAs MMICs

The die should be attached directly to the ground plane eutectically or with conductive epoxy (see HMC general Handling, Mounting, Bonding Note).

50 Ohm Microstrip transmission lines on 0.127mm (5 mil) thick alumina thin film substrates are recommended for bringing RF to and from the chip (Figure 1). If 0.254mm (10 mil) thick alumina thin film substrates must be used, the die should be raised 0.150mm (6 mils) so that the surface of the die is coplanar with the surface of the substrate. One way to accomplish this is to attach the 0.102mm (4 mil) thick die to a 0.150mm (6 mil) thick molybdenum heat spreader (moly-tab) which is then attached to the ground plane (Figure 2).

Microstrip substrates should be located as close to the die as possible in order to minimize bond wire length. Typical die-to-substrate spacing is 0.076mm to 0.152 mm (3 to 6 mils).

Handling Precautions

Follow these precautions to avoid permanent damage.

Storage: All bare die are placed in either Waffle or Gel based ESD protective containers, and then sealed in an ESD protective bag for shipment. Once the sealed ESD protective bag has been opened, all die should be stored in a dry nitrogen environment.

Cleanliness: Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.

Static Sensitivity: Follow ESD precautions to protect against $> \pm 150V$ ESD strikes.

Transients: Suppress instrument and bias supply transients while bias is applied. Use shielded signal and bias cables to minimize inductive pick-up.

General Handling: Handle the chip along the edges with a vacuum collet

or with a sharp pair of bent tweezers. The surface of the chip may have fragile air bridges and should not be touched with vacuum collet, tweezers, or fingers.

Mounting

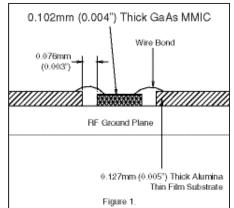
The chip is back-metallized and can be die mounted with AuSn eutectic preforms or with electrically conductive epoxy. The mounting surface should be clean and flat.

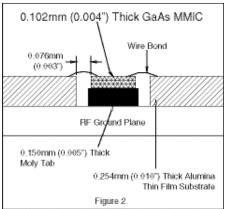
Eutectic Die Attach: A 80/20 gold tin preform is recommended with a work surface temperature of 255 °C and a tool temperature of 265 °C. When hot 90/10 nitrogen/hydrogen gas is applied, tool tip temperature should be 290 °C. DO NOT expose the chip to a temperature greater than 320 °C for more than 20 seconds. No more than 3 seconds of scrubbing should be required for attachment.

Epoxy Die Attach: Apply a minimum amount of epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip once it is placed into position. Cure epoxy per the manufacturer's schedule.

Wire Bonding

Ball or wedge bond with 0.025mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31mm (12 mils).





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Notes

HMC1110

GaAs MMIC X6 ACTIVE FREQUENCY MULTIPLIER, 71 - 86 GHz

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